



**TMMBAT 42**  
**TMMBAT 43**

## SMALL SIGNAL SCHOTTKY DIODES

### DESCRIPTION

General purpose, metal to silicon diodes featuring very low turn-on voltage fast switching.

These devices have integrated protection against excessive voltage such as electrostatic discharges.

**MINIMELF**  
(Glass)

### ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		Value	Unit
$V_{RRM}$	Repetitive Peak Reverse Voltage		30	V
$I_F$	Forward Continuous Current	$T_I = 25^\circ\text{C}$	200	mA
$I_{FRM}$	Repetitive Peak Forward Current	$t_p \leq 1\text{s}$ $\delta \leq 0.5$	500	mA
$I_{FSM}$	Surge non Repetitive Forward Current	$t_p = 10\text{ms}$	4	A
$P_{tot}$	Power Dissipation	$T_I = 65^\circ\text{C}$	200	mW
$T_{stg}$ $T_j$	Storage and Junction Temperature Range		- 65 to 150 - 65 to 125	$^\circ\text{C}$ $^\circ\text{C}$
$T_L$	Maximum Temperature for Soldering during 15s		260	$^\circ\text{C}$

### THERMAL RESISTANCE

Symbol	Test Conditions	Value	Unit
$R_{th(j-l)}$	Junction-leads	300	$^\circ\text{C}/\text{W}$

**ELECTRICAL CHARACTERISTICS**
**STATIC CHARACTERISTICS**

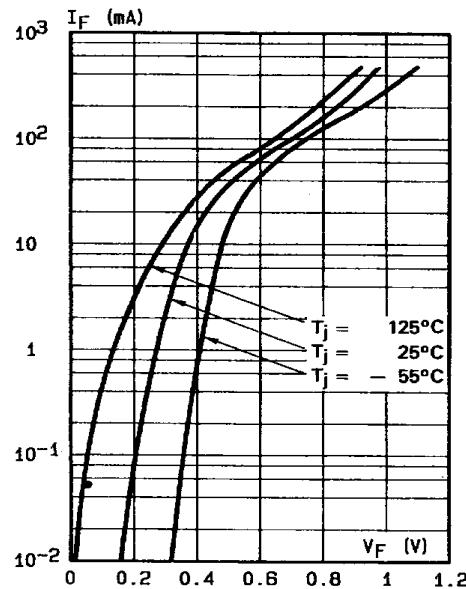
Symbol	Test Conditions			Min.	Typ.	Max.	Unit	
$V_{BR}$	$T_j = 25^\circ\text{C}$ $I_R = 100\mu\text{A}$			30			V	
$V_F^*$	$T_j = 25^\circ\text{C}$ $I_F = 200\text{mA}$					1	V	
	$T_j = 25^\circ\text{C}$	$I_F = 10\text{mA}$	BAT 42			0.4		
	$T_j = 25^\circ\text{C}$	$I_F = 50\text{mA}$				0.65		
	$T_j = 25^\circ\text{C}$	$I_F = 2\text{mA}$	BAT 43	0.26		0.33		
	$T_j = 25^\circ\text{C}$	$I_F = 15\text{mA}$				0.45		
$I_R^*$	$T_j = 25^\circ\text{C}$ $V_R = 25\text{V}$					0.5	$\mu\text{A}$	
	$T_j = 100^\circ\text{C}$					100		

**DYNAMIC CHARACTERISTICS**

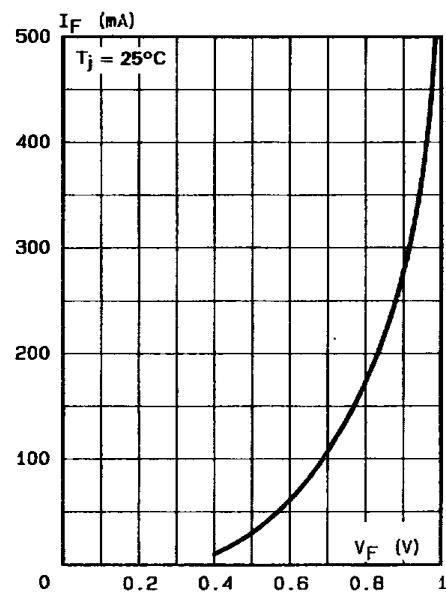
Symbol	Test Conditions			Min.	Typ.	Max.	Unit
C	$T_j = 25^\circ\text{C}$ $V_R = 1\text{V}$ $f = 1\text{MHz}$				7		pF
trr	$T_j = 25^\circ\text{C}$ $I_F = 10\text{mA}$ $I_R = 10\text{mA}$ $i_{rr} = 1\text{mA}$ $R_L = 100\Omega$					5	ns
$\eta$	$T_j = 25^\circ\text{C}$ $R_L = 15\text{K}\Omega$ $C_L = 300\text{pF}$ $f = 45\text{MHz}$ $V_i = 2\text{V}$			80			%

\* Pulse test:  $t_p \leq 300\mu\text{s}$   $\delta < 2\%$ .

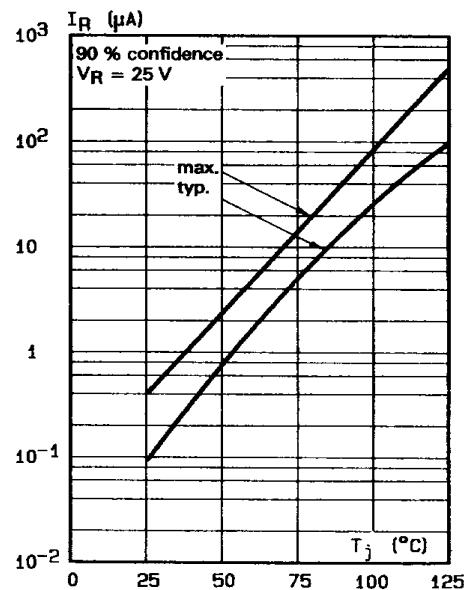
**Figure 1. Forward current versus forward voltage at different temperatures (typical values).**



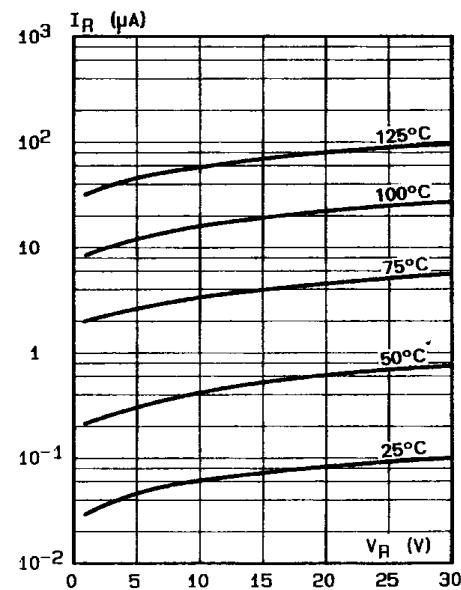
**Figure 2. Forward current versus forward voltage (typical values).**



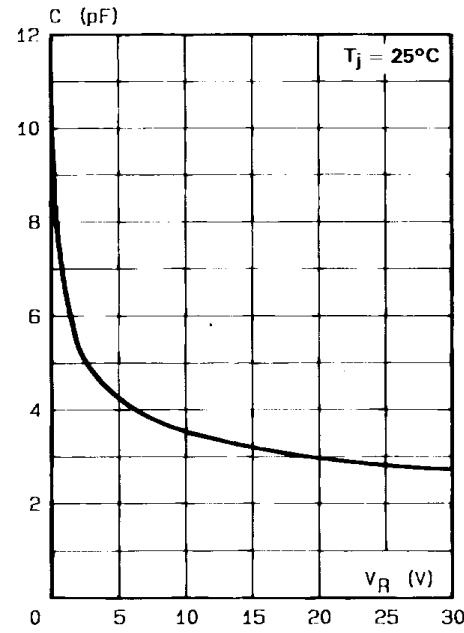
**Figure 3. Reverse current versus junction temperature.**



**Figure 4. Reverse current versus continuous reverse voltage (typical values).**



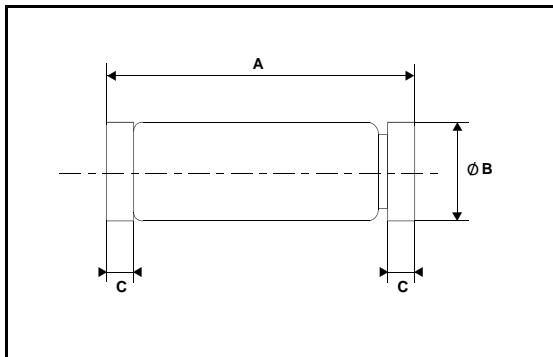
**Figure 5. Forward current versus forward voltage (typical values).**



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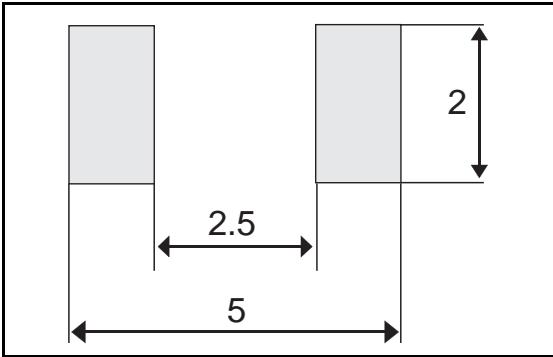
### PACKAGE MECHANICAL DATA

MINIMELF Glass



REF.	DIMENSIONS					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	3.30	3.40	3.6	0.130	0.134	0.142
B	1.59	1.60	1.62	0.063	0.063	0.064
C	0.40	0.45	0.50	0.016	0.018	0.020
D		1.50			0.059	

### FOOT PRINT DIMENSIONS (Millimeter)



Marking: ring at cathode end.  
Weight: 0.05g

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